

Not for New Design

Vishay Semiconductors

Low Profile Transceiver Module PIN Photodiode and Infrared Emitter

Description

The miniaturized TFDU2201 is an ideal PIN photodiode transmitter combination in a unique package for applications in telecommunications like mobile phones and pagers. The device is mechanically designed for lowest profile with a height of only 2.8 mm. The device is designed to be compatible to the IrDA standard when using an external receiver IC and IRED driver.





Features

- Package Dimension: L 7.1 mm x W 4.55 mm x H 2.75 mm
- SMD Side View
- · Fast PIN Photodiode for Sir abd FIR
- · Detector with High Efficiency and High Speed at Low Bias Voltage

Only 30 mA IRED Peak Current During Transmission for IrDA SIR Low Power Standard

Applications

Mobile Phones, Pagers, Personal Digital Assistants (PDA), Handheld Battery Operated Equipment

Parts Table

Part	Description	Qty / Reel
TFDU2201-TR1	Orientated in carrier tape for side view mounting	750 pcs.
TFDU2201-TR3	Orientated in carrier tape for side view mounting	2250 pcs.

Pin Description

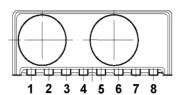
Pin Number	Function	Description	I/O	Active
1	IRED GND	IRED Cathode, Ground, to be used as heat sink		
2	IRED GND	IRED Cathode, Ground, to be used as heat sink		
3	IRED Anode	IRED Anode, to be driven by a current source		
4	NC			
5	NC			
6	NC			
7	D _{anode}	Detector Anode		
8	D _{cathode}	Detector Cathode		

Document Number 82539 www.vishay.com Rev. 1.1, 17-Oct-03



Pinout

TFDU2201 weight 100 mg



18228



Absolute Maximum Ratings

Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Photo pin diode, reverse voltage range		V _r	- 0.3		12	V
Photo pin diode, reverse photo current					10	mA
Average IRED current		I _{IRED(DC)}			100	mA
Repetitive pulsed IRED current	< 90 μs, t _{on} < 20 %	I _{IRED(RP)}			550	mA
IRED, reverse voltage range		V_{rIRED}	- 0.3		5	V
Power dissipation	see Figure 3	P _{tot}			200	mW
Juntion temperature		TJ			125	°C
Ambient temperature range (operating)		T _{amb}	- 25		+ 85	°C
Storage temperature range		T _{stg}	- 40		+ 85	°C
Soldering temperature	t = 20 s @ 215 °C, see Vishay Telefunken IrDA Design Guide			215	240	°C
Virtual source size	Method: (1 - 1/e) encircled energy	d		2		mm

Compatible to Class 1 opration of IEC 60825 or EN60825 with worst case IrDA SIR pulse pattern, 115.2 kbit/s

Electrical Characteristics

Transceiver

Tested for the following parameters (T=25°C, unless otherwise stated)

Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Supported data rates	base band		9.6		4000	kbit/s

www.vishay.com

Document Number 82539

Rev. 1.1, 17-Oct-03



Optoelectronic Characteristics

Receiver

Tested for the following parameters (T = 25 °:C, unless otherwise stated)

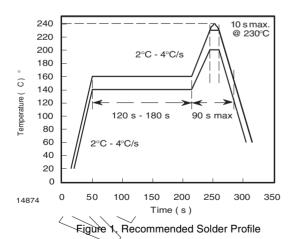
Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Spectral sensitivity	$\mid \alpha \mid \leq \pm 15$ °, $V_r = 2 V$,	S_λ	1.0	1.2	1.8	nA/(mW/m ²)
	$\lambda = 875 \text{ nm}$, ,
Bias voltage range, detector		V _{Rev}			12	V
Reverse leakage current				0.2		nA
Spectral bandwith		λ	800		950	nm
Max. operating irradiance	$\mid \alpha \mid \leq \pm 90$ °C, $V_{CC} = 2 \text{ V}$	E _{e, max}	8000	15000		W/m ²
Rise time @ load : $R = 50 \Omega$	$V_r = 2 \text{ V}, \lambda = 875 \text{ nm}$	t _r		40		ns
Fall time @ load : R = 50 Ω	$V_r = 2 \text{ V}, \ \lambda = 875 \text{ nm}$	t _r		40		ns

Transmitter

Tested for the following parameters (T = 25 °:C, unless otherwise stated)

Parameter	Test Conditions	Symbol	Min	Тур.	Max	Unit
Forward current operating condition for low power IrDA operation	I_e = 4 to 28 mW/sr in $ \alpha \le \pm 15$ °	I _{F1}		30		mA
Output radiant intensity	$\mid \alpha \mid \leq \pm 15$ °, $I_{F1} = 35$ mA, 25 % duty cycle	Ι _e	4	8	14	mW/sr
	$\mid \alpha \mid \leq \pm$ 15 °, I_{F1} = 350 mA, 25 % duty cycle	Ι _e	35			mW/sr
Forward voltage	I _f = 50 mA	V _f	1.2		1.45	V
Peak emission wavelength		λ_{p}	880		900	nm
Spectral emission bandwith				45		nm
Optical rise/fall time	2 MHz square wave signal (duty cycle 1:1)			38		ns

Recommended Solder Profile



Current Derating Diagram

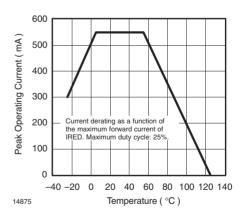
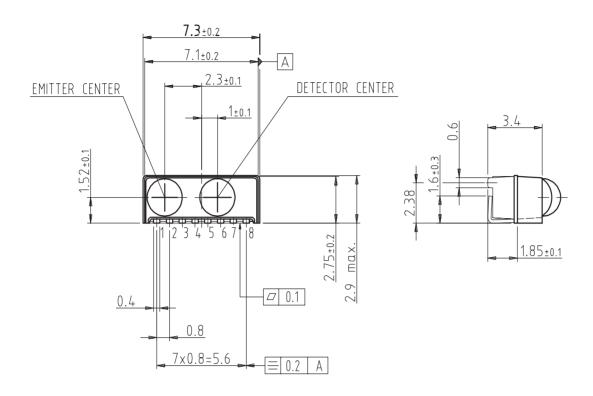


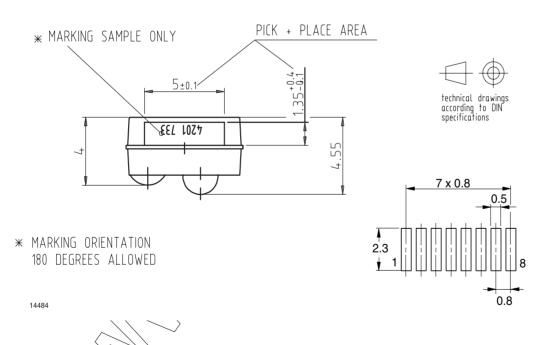
Figure 2. Current Derating Diagram

Document Number 82539 www.vishay.com Rev. 1.1, 17-Oct-03

VISHAY

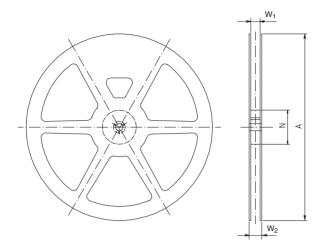
Package Dimensions in mm

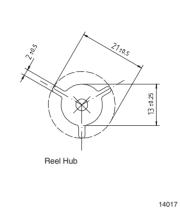




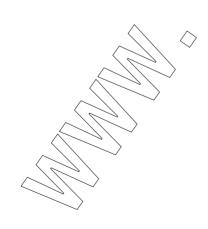


Reel Dimensions





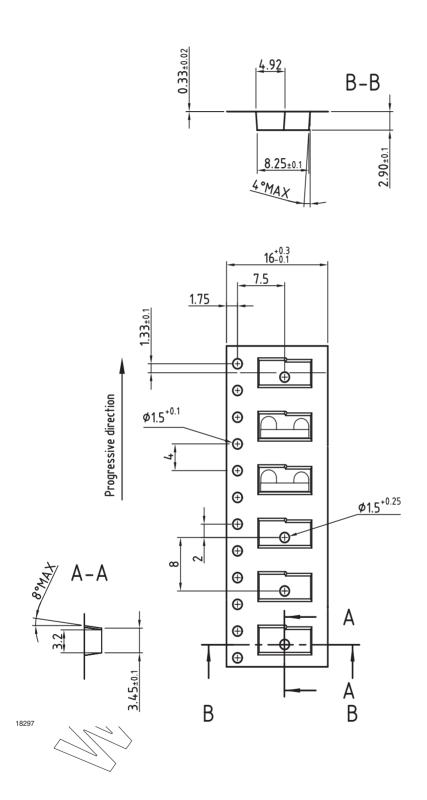
Tape Width	A max.	N	W ₁ min.	W ₂ max.	W ₃ min.	W ₃ max.
mm	mm	mm	mm	mm	mm	mm
24	330	60	24.4	30.4	23.9	27.4



Document Number 82539 Rev. 1.1, 17-Oct-03

VISHAY

Tape Dimensions in mm





Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B/and/C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our sergiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

> Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

www.vishay.com

Rev. 1.1, 17-Oct-03